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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.
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09/295,709 04/21/99 JIANG

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EXAMINER

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ART UNIT

PAPER NUMBER

2814

DATE MAILED:

06/20/01

Please find below and/or attached an Office communication concerning this application or proceeding.

Commissioner of Patents and Trademarks

Office Action Summary

Application No.

09/295,709

Applicant(s)

JIANG ET AL.

Examiner

David E Graybill

Art Unit

2814

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136 (a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 29 March 2001.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 7,8,13-16,21 and 25-63 is/are pending in the application.
- 4a) Of the above claim(s) 13,14,21,32-37,45,52-56,62 and 63 is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 7,8,15,16,25-31,38-44,46-51 and 57-61 is/are rejected.
- 7) ☒ Claim(s) _____ is/are objected to.
- 8) ☐ Claims _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are objected to by the Examiner.
- 11) ☐ The proposed drawing correction filed on _____ is: a) ☐ approved b) ☐ disapproved.
- 12) ☐ The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. § 119

- 13) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- * See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgement is made of a claim for domestic priority under 35 U.S.C. § 119(e).

Attachment(s)

- 15) ☒ Notice of References Cited (PTO-892)
- 16) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 17) ☐ Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____.
- 18) ☐ Interview Summary (PTO-413) Paper No(s). _____.
- 19) ☐ Notice of Informal Patent Application (PTO-152)
- 20) ☐ Other: _____.

Application/Control Number: 09/295,709
Art Unit: 2814

Page 2

Claims 13, 14, 21, 32-37, 45, 52-56, 62 and 63 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made **without** traverse in Paper No. 8.

The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

The amendment filed 1-9-01 is objected to under 35 U.S.C. 132 because it introduces new matter into the disclosure. 35 U.S.C. 132 states that no amendment shall introduce new matter into the disclosure of the invention. The added material which is not supported by the original disclosure is the claims 15, 29, 51, 52 and 57 limitations wherein the conductive material comprises both a generally planar first surface and a height-to-width ratio of at least approximately 3 to 1, and all of the limitations of claims 38-40, 42, and 58-61. To further clarify the rejection of claims 38-40, 42 and 58-61, it is noted that there is no original disclosure wherein the conductive bumps comprise the limitations of claims 38-40, 42 and 58-61.

Application/Control Number: 09/295,709
Art Unit: 2814

Page 3

Applicant is required to cancel the new matter in the reply to this Office Action.

Claims 15, 16, 29, 38-44, 51 and 57-61 are rejected under 35 U.S.C. 112, first paragraph, as containing subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

The non-described subject matter is the claims 15, 29, 51, 52 and 57 limitations wherein the conductive material comprises both a generally planar first surface and a height-to-width ratio of at least approximately 3 to 1, and all of the limitations of claims 38-40, 42, and 58-61.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(a) the invention was known or used by others in this country, or patented or described in a printed publication in this or a foreign country, before the invention thereof by the applicant for a patent.

Claims 7, 8, 15, 16, 25-31, 38-44, 46-51 and 57-61 are rejected under 35 U.S.C. 102(a) as being anticipated by Pasch (5468681).

Art Unit: 2814

7. A semiconductor substrate 1850 including at least one adhesive patch 1812 comprised of a viscous adhesive material, the at least one adhesive patch including, a first surface 1825e adjacent said semiconductor substrate and a second, smaller surface 1825c opposite said first surface exhibiting a generally planar portion over a substantial portion thereof.

25. The semiconductor substrate of 7, wherein said viscous adhesive material of said at least one adhesive patch comprises at least one of the group consisting of a polyimide, a phenolic resin, a thermoplastic, and a thermosetting plastic ("epoxy").

26. The semiconductor substrate of 7, wherein said at least one adhesive patch comprises at least one lateral edge exhibiting an angle of repose of at least approximately 20 degrees.

27. The semiconductor substrate of 7, wherein said at least one adhesive patch comprises at least one trailing edge exhibiting an angle of repose of at least approximately 13 degrees.

28. The semiconductor substrate of 7, wherein said at least one adhesive patch comprises at least one leading edge exhibiting an angle of repose of at least approximately 20 degrees.

29. The semiconductor substrate of 7, wherein said at least one adhesive patch comprises a height-to-width ratio of at least approximately 3 to 1.

Application/Control Number: 09/295,709
Art Unit: 2814

Page 5

15. A flip-chip including at least one conductive bump 1812 comprised of a viscous conductive material, the at least one conductive bump exhibiting height-to-width ratio of at least approximately 3 to 1 and including a first surface 1825e adjacent said flip-chip and a second surface 1825c opposite said first surface exhibiting a generally planar portion over a substantial portion thereof.

38. The flip-chip of 15, wherein said at least one conductive bump comprises at least one lateral edge exhibiting an angle of repose of at least approximately 20 degrees.

39. The flip-chip of 15, wherein said at least one conductive bump comprises at least one trailing edge exhibiting an angle of repose of at least approximately 12 degrees.

40. The flip-chip of 15, wherein said at least one conductive bump comprises at least one leading edge exhibiting an angle of repose of at least approximately 20 degrees.

41. The flip-chip of 15, wherein said conductive material of said at least one conductive bump comprises a conductive polymer material.

42. The flip-chip of 15, wherein said viscous conductive material of said at least one conductive bump comprises at least one of the group consisting of a polyimide, a phenolic resin, a thermoplastic, and a thermosetting plastic.

46. A semiconductor substrate 1850 including at least one adhesive patch 1812 comprised of a viscous adhesive material, the at least one adhesive patch including a first surface 1825e adjacent said semiconductor substrate and a second surface 1825c opposite said first surface, said second surface exhibiting a generally planar portion over a substantial portion thereof.

47. The semiconductor substrate of 46, wherein said viscously dispensed adhesive material comprises at least one of the group consisting of a polyimide, a phenolic resin, a thermoplastic, and a thermosetting plastic.

48. The semiconductor substrate of 46, wherein said at least one adhesive patch comprises at least one lateral edge exhibiting an angle of repose of at least approximately 20 degrees.

49. The semiconductor substrate of 46, wherein said at least one adhesive patch comprises at least one trailing edge exhibiting an angle of repose of at least approximately 13 degrees.

50. The semiconductor substrate of 46, wherein said at least one adhesive patch comprises at least one leading edge exhibiting an angle of repose of at least approximately 20 degrees.

51. The semiconductor substrate of 46, wherein said at least one adhesive patch exhibits a height-to-width ratio of at least approximately 3 to 1.

58. The flip-chip of 57, wherein said viscous conductive material of said at least one conductive bump comprises at least one of the group consisting of a polyimide, a phenolic resin, a thermoplastic, and a thermosetting plastic.

57. A flip-chip 1850 including at least one conductive bump 1812 comprised of a viscous conductive material, the at least one conductive bump exhibiting a height-to-width ratio of at least approximately 3 to 1 and including a first surface 1825e adjacent said flip-chip and a second surface 1825c opposite said first surface, said second surface exhibiting a generally planar portion over a substantial portion thereof.

59. The flip-chip of 57, wherein said at least one conductive bump comprises at least one lateral edge exhibiting an angle of repose of at least approximately 20 degrees.

60. The flip-chip of 57, wherein said at least one conductive bump comprises at least one trailing edge exhibiting an angle of repose of at least approximately 13 degrees.

61. The flip-chip of 57, wherein said at least one conductive bump comprises at least one leading edge exhibiting an angle of repose of at least approximately 20 degrees.

Although Pasch does not appear to explicitly teach the particular claimed edge angles of repose, these limitations are illustrated in Figure 18d and taught, as cited, "globs 1825a

Application/Control Number: 09/295,709
Art Unit: 2814

Page 8

contact the pads and spread out to form conductive liquid seals 1825," and are an inherent property of the spread out globs.

Also, although Pasch does not appear to explicitly teach the process limitations of claims 7, 8, 15, 16, 30, 31, 43 and 44, the product of Pasch inherently possesses the structural characteristics imparted by the process limitations. See *In re Fitzgerald, Sanders, and Bagheri*, 205 USPQ 594 (CCPA 1980).

Applicant's remarks filed 3-29-01 have been fully considered and rendered moot by the rejection *supra*.

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Application/Control Number: 09/295,709

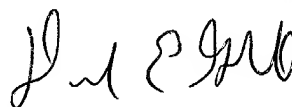
Page 9

Art Unit: 2814

Any telephone inquiry of a general nature or relating to the status (MPEP 203.08) of this application or proceeding should be directed to the group receptionist whose telephone number is 703-308-1782.

Any telephone inquiry concerning this communication or earlier communications from the examiner should be directed to David E. Graybill at (703) 308-2947. Regular office hours: Monday through Friday, 8:30 a.m. to 6:00 p.m.

The fax phone number for group 2800 is 703/305-3431.



David E. Graybill
Primary Examiner
Art Unit 2814

D.G.
15-Jun-01